# Triacs

## **Silicon Bidirectional Thyristors**

Designed for high performance full-wave ac control applications where high noise immunity and high commutating di/dt are required.

### Features

- Blocking Voltage to 800 Volts
- On-State Current Rating of 8.0 Amperes RMS at 100°C
- Uniform Gate Trigger Currents in Three Quadrants
- High Immunity to dv/dt 250 V/µs minimum at 125°C
- Minimizes Snubber Networks for Protection
- Industry Standard TO-220AB Package
- High Commutating di/dt 6.5 A/ms minimum at 125°C
- These Devices are Pb-Free and are RoHS Compliant\*

### **MAXIMUM RATINGS** (T<sub>J</sub> = $25^{\circ}$ C unless otherwise noted)

Characteristic	Symbol	Value	Unit
Peak Repetitive Off–State Voltage <sup>,</sup> (Note 1) ( $T_J = -40$ to 125°C, Sine Wave, 50 to 60 Hz, Gate Open)	V <sub>DRM,</sub> V <sub>RRM</sub>		V
MAC8DG MAC8MG MAC8NG		400 600 800	
On-State RMS Current, (Full Cycle Sine Wave, 60 Hz, T <sub>C</sub> = 100°C)	I <sub>T(RMS)</sub>	8.0	A
Peak Non-Repetitive Surge Current (One Full Cycle Sine Wave, 60 Hz, T <sub>J</sub> = 125°C)	I <sub>TSM</sub>	80	A
Circuit Fusing Consideration (t = 8.3 ms)	l <sup>2</sup> t	26	A <sup>2</sup> s
Peak Gate Power (Pulse Width $\leq$ 1.0 $\mu$ s, T <sub>C</sub> = 80°C)	P <sub>GM</sub>	16	W
Average Gate Power (t = 8.3 ms, $T_C = 80^{\circ}C$ )	P <sub>G(AV)</sub>	0.35	W
Operating Junction Temperature Range	TJ	-40 to +125	°C
Storage Temperature Range	T <sub>stg</sub>	-40 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

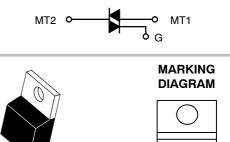
 V<sub>DRM</sub> and V<sub>RRM</sub> for all types can be applied on a continuous basis. Blocking voltages shall not be tested with a constant current source such that the voltage ratings of the devices are exceeded.

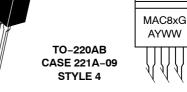


### **ON Semiconductor®**

http://onsemi.com







x = D, M, or N A = Assembly Location (Optional)\* Y = Year

Y = Year

WW = Work Week

G = Pb-Free Package

\* The Assembly Location code (A) is optional. In cases where the Assembly Location is stamped on the package the assembly code may be blank.

PIN ASSIGNMENT		
1	Main Terminal 1	
2	Main Terminal 2	
3	Gate	
4	Main Terminal 2	

### **ORDERING INFORMATION**

Device	Package	Shipping		
MAC8DG	TO-220AB (Pb-Free)	50 Units / Rail		
MAC8MG	TO-220AB (Pb-Free)	50 Units / Rail		
MAC8NG	TO-220AB (Pb-Free)	50 Units / Rail		

\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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### THERMAL CHARACTERISTICS

Characteristic	Symbol	Value	Unit
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	2.2	°C/W
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	62.5	°C/W
Maximum Lead Temperature for Soldering Purposes 1/8" from Case for 10 Seconds	ΤL	260	°C

### **ELECTRICAL CHARACTERISTICS** ( $T_J$ = 25°C unless otherwise noted; Electricals apply in both directions)

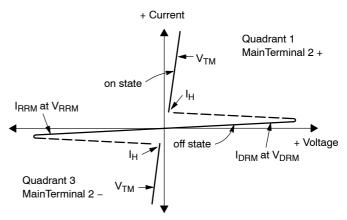
Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS	1				
Peak Repetitive Blocking Current (V <sub>D</sub> = Rated V <sub>DRM</sub> , V <sub>RRM</sub> ; Gate Open) $T_J$ = 25°C $T_J$ = 125°C				0.01 2.0	mA
ON CHARACTERISTICS		•	•	•	
Peak On-State Voltage (Note 2), ( $I_{TM} = \pm 11 \text{ A Peak}$ )	V <sub>TM</sub>	-	1.2	1.6	V
Gate Trigger Current (Continuous DC) (V <sub>D</sub> = 12 V, R <sub>L</sub> = 100 Ω) MT2(+), G(+) MT2(+), G(-) MT2(-), G(-)	I <sub>GT</sub>	5.0 5.0 5.0	13 16 18	35 35 35	mA
Holding Current, (V <sub>D</sub> = 12 V, Gate Open, Initiating Current = $\pm$ 150 mA)	Ι <sub>Η</sub>	-	20	40	mA
Latching Current (V <sub>D</sub> = 24 V, I <sub>G</sub> = 35 mA), MT2(+), G(+); MT2(-), G(-) MT2(+), G(-)	١L		20 30	50 80	mA
Gate Trigger Voltage (V <sub>D</sub> = 12 V, R <sub>L</sub> = 100 Ω) MT2(+), G(+) MT2(+), G(-) MT2(-), G(-)	V <sub>GT</sub>	0.5 0.5 0.5	0.69 0.77 0.72	1.5 1.5 1.5	V
Gate Non–Trigger Voltage (V <sub>D</sub> = 12 V, R <sub>L</sub> = 100 Ω, T <sub>J</sub> = 125°C) MT2(+), G(+); MT2(+), G(-); MT2(-), G(-)	V <sub>GD</sub>	0.2	_	_	V
DYNAMIC CHARACTERISTICS				•	
Rate of Change of Commutating Current See Figure 10.( $V_D = 400 \text{ V}$ , $I_{TM} = 4.4 \text{ A}$ , Commutating dv/dt = 18 V/µs,Gate Open, $T_J = 125^{\circ}$ C, f = 250 Hz, No Snubber) $C_L = 10 \ \mu\text{F}$ $L_L = 40 \text{ mH}$	(di/dt) <sub>c</sub>	6.5	-	-	A/ms
Critical Rate of Rise of Off-State Voltage (V <sub>D</sub> = Rated V <sub>DRM</sub> , Exponential Waveform, Gate Open, $T_J$ = 125°C)	dv/dt	250	_	-	V/μs

2. Indicates Pulse Test: Pulse Width  $\leq$  2.0 ms, Duty Cycle  $\leq$  2%.

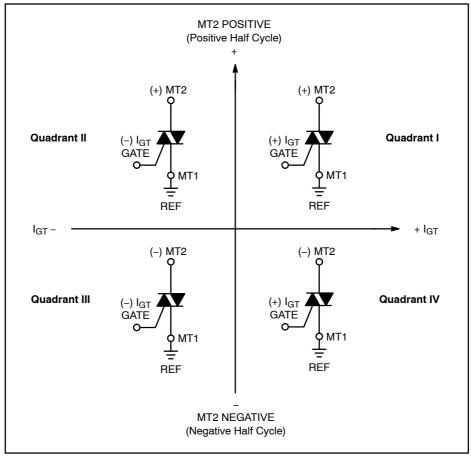
# www.BDhtp://http://com/ON/

### Voltage Current Characteristic of Triacs (Bidirectional Device)

Symbol	Parameter
V <sub>DRM</sub>	Peak Repetitive Forward Off State Voltage
I <sub>DRM</sub>	Peak Forward Blocking Current
V <sub>RRM</sub>	Peak Repetitive Reverse Off State Voltage
I <sub>RRM</sub>	Peak Reverse Blocking Current
V <sub>TM</sub>	Maximum On State Voltage
I <sub>H</sub>	Holding Current



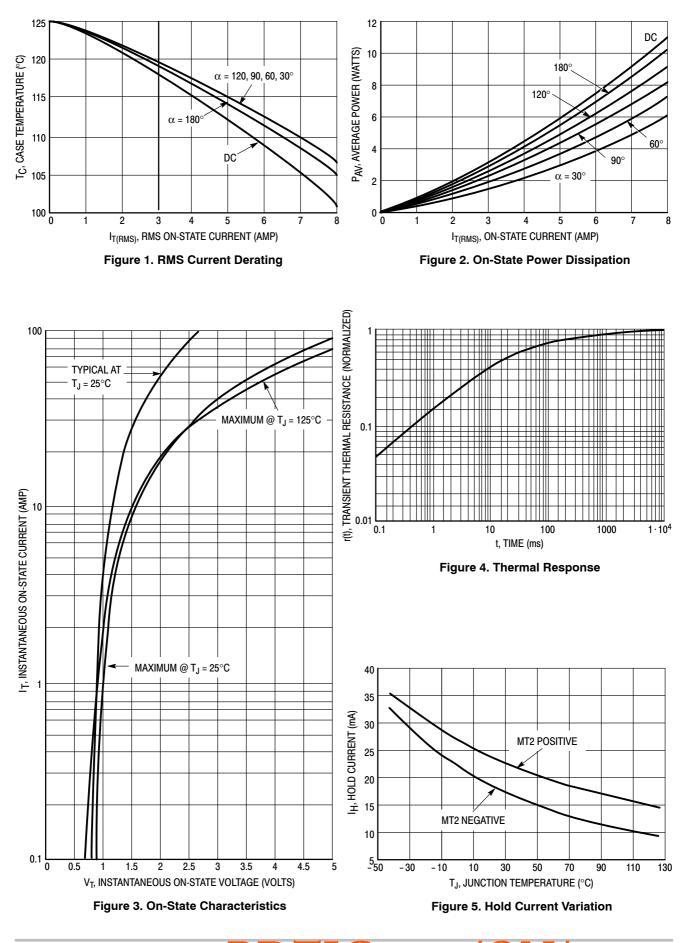
### **Quadrant Definitions for a Triac**



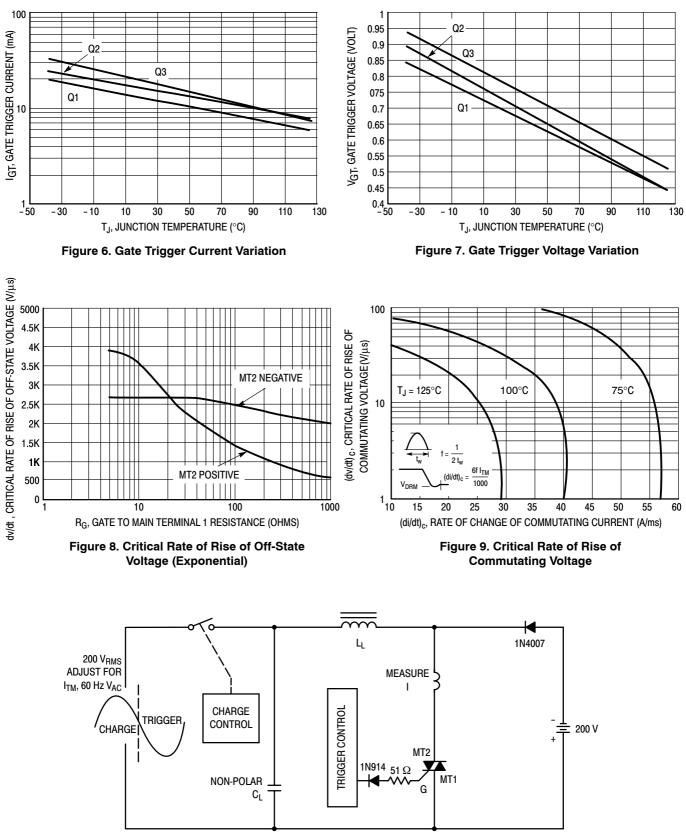
All polarities are referenced to MT1.

With in-phase signals (using standard AC lines) quadrants I and III are used.

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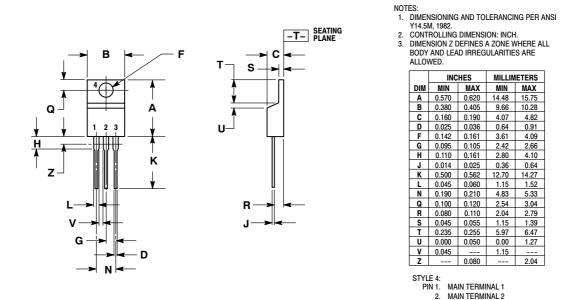
Note: Component values are for verification of rated (di/dt)c. See AN1048 for additional information.

Figure 10. Simplified Test Circuit to Measure the Critical Rate of Rise of Commutating Current (di/dt)

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### PACKAGE DIMENSIONS

TO-220 CASE 221A-09 ISSUE AG



GATE
MAIN

MAIN TERMINAL 2

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